

ULN200x, ULQ200x High-Voltage, High-Current Darlington Transistor Arrays

1 Features

- 500mA-rated collector current (single output)
- High-voltage outputs: 50V
- Output clamp diodes
- Inputs compatible with various types of logic
- Relay-driver applications

2 Applications

- Relay Drivers
- Stepper and DC Brushed Motor Drivers
- Lamp Drivers
- Display Drivers (LED and Gas Discharge)
- Line Drivers
- Logic Buffers

3 Description

The ULx200xA devices are high-voltage, high-current Darlington transistor arrays. Each consists of seven NPN Darlington pairs that feature high-voltage outputs with common-cathode clamp diodes for switching inductive loads.

The collector-current rating of a single Darlington pair is 500mA. The Darlington pairs can be paralleled for higher current capability. Applications include relay drivers, hammer drivers, lamp drivers, display drivers (LED and gas discharge), line drivers, and logic buffers. For 100V (otherwise interchangeable) versions of the ULx2003A devices, see the [SLRS023](#) data sheet for the SN75468 and SN75469 devices.

The ULN2002A device is designed specifically for use with 14V to 25V PMOS devices. Each input of this device has a Zener diode and resistor in series to control the input current to a safe limit. The ULx2003A devices have a 2.7k Ω series base resistor for each Darlington pair for operation directly with TTL or 5V CMOS devices.

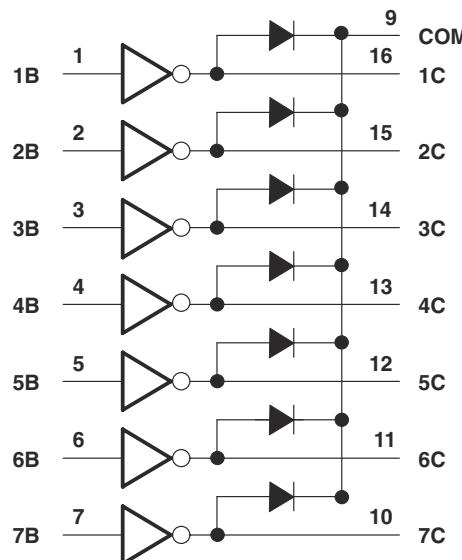
The ULx2004A devices have a 10.5k Ω series base resistor to allow operation directly from CMOS devices that use supply voltages of 6V to 15V. The required input current of the ULx2004A device is below that of the ULx2003A devices, and the required voltage is less than that required by the ULN2002A device.

Package Information

PART NUMBER	PACKAGE ⁽¹⁾	PACKAGE SIZE ⁽²⁾
ULN200xAD	SOIC (16)	9.90mm × 3.91mm
ULN200xAN	PDIP (16)	19.30mm × 6.35mm
ULN200xANS	SOP (16)	10.30mm × 5.30mm
ULN200xAPW	TSSOP (16)	5.00mm × 4.40mm
ULN2003ADYY	SOT (16)	4.20mm × 2.00mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

(2) The package size (length × width) is a nominal value and includes pins, where applicable.



Simplified Block Diagram



An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.

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4 Pin Configuration and Functions

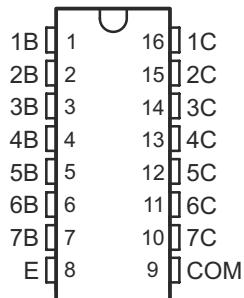


Figure 4-1. D, N, NS, and PW Package 16-Pin SOIC, PDIP, SO, and TSSOP Top View

Table 4-1. Pin Functions

PIN		I/O ⁽¹⁾	DESCRIPTION
NAME	NO.		
1B	1	I	Channel 1 through 7 Darlington base input
2B	2		
3B	3		
4B	4		
5B	5		
6B	6		
7B	7		
1C	16	O	Channel 1 through 7 Darlington collector output
2C	15		
3C	14		
4C	13		
5C	12		
6C	11		
7C	10		
COM	9	—	Common cathode node for flyback diodes (required for inductive loads)
E	8	—	Common emitter shared by all channels (typically tied to ground)

(1) I = Input, O = Output

5 Specifications

5.1 Absolute Maximum Ratings

at 25°C free-air temperature (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT
V _{CC}	Collector-emitter voltage		50	V
	Clamp diode reverse voltage ⁽²⁾		50	V
V _I	Input voltage ⁽²⁾		30	V
	Peak collector current, See Figure 5-4 and Figure 5-5		500	mA
I _{OK}	Output clamp current		500	mA
	Total emitter-terminal current		-2.5	A
T _A	Operating free-air temperature range	ULN200xA	-40	70
		ULN200xAI	-40	105
		ULQ200xA	-40	85
		ULQ200xAT	-40	105
		ULN2004ADR	-40	105
T _J	Operating virtual junction temperature		150	°C
	Lead temperature for 1.6 mm (1/16 inch) from case for 10 seconds		260	°C
T _{stg}	Storage temperature		-65	150
				°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltage values are with respect to the emitter/substrate terminal E, unless otherwise noted.

5.2 ESD Ratings

		VALUE	UNIT
V _(ESD)	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±2000
		Charged device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	±500

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
V _{CC}	Collector-emitter voltage (non-V devices)	0	50	V
T _J	Junction temperature	-40	125	°C

5.4 Thermal Information

THERMAL METRIC ⁽¹⁾		ULx200x					UNIT
		D (SOIC)	N (PDIP)	NS (SO)	PW (TSSOP)	DYY (SOT)	
		16 PINS	16 PINS	16 PINS	16 PINS	16 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	88.6	66.7	95.0	114.1	123.1	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	50.1	54.2	53.3	50.3	59.6	°C/W
R _{θJB}	Junction-to-board thermal resistance	49.8	46.7	57.2	59.3	56.5	°C/W
Ψ _{JT}	Junction-to-top characterization parameter	12.4	33.7	19.6	9.7	3.2	°C/W

5.4 Thermal Information (continued)

THERMAL METRIC ⁽¹⁾		ULx200x					UNIT
		D (SOIC)	N (PDIP)	NS (SO)	PW (TSSOP)	DYY (SOT)	
		16 PINS	16 PINS	16 PINS	16 PINS	16 PINS	
Ψ_{JB}	Junction-to-board characterization parameter	49.3	46.4	56.8	58.9	56.0	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report, [SPRA953](#).

5.5 Electrical Characteristics: ULN2002A

$T_A = 25^\circ\text{C}$

PARAMETER		TEST FIGURE	TEST CONDITIONS		ULN2002A			UNIT
					MIN	TYP	MAX	
$V_{I(on)}$	ON-state input voltage	Figure 6-6	$V_{CE} = 2 \text{ V}$	$I_C = 300 \text{ mA}$			13	V
V_{OH}	High-level output voltage after switching	Figure 6-10	$V_S = 50 \text{ V}$	$I_O = 300 \text{ mA}$	$V_S - 20$			mV
$V_{CE(sat)}$	Collector-emitter saturation voltage	Figure 6-4	$I_I = 250 \mu\text{A}$	$I_C = 100 \text{ mA}$	0.9	1.1		V
			$I_I = 350 \mu\text{A}$	$I_C = 200 \text{ mA}$	1	1.3		
			$I_I = 500 \mu\text{A}$	$I_C = 350 \text{ mA}$	1.2	1.6		
V_F	Clamp forward voltage	Figure 6-7	$I_F = 350 \text{ mA}$		1.7	2		V
I_{CEX}	Collector cutoff current	Figure 6-1	$V_{CE} = 50 \text{ V}$	$I_I = 0$		50		μA
		Figure 6-2	$V_{CE} = 50 \text{ V}$	$I_I = 0$	100			
			$T_A = 70^\circ\text{C}$	$V_I = 6 \text{ V}$		500		
$I_{I(off)}$	OFF-state input current	Figure 6-2	$V_{CE} = 50 \text{ V}$	$I_C = 500 \mu\text{A}$	50	65		μA
I_I	Input current	Figure 6-3	$V_I = 17 \text{ V}$		0.82	1.25		mA
I_R	Clamp reverse current	Figure 6-6	$V_R = 50 \text{ V}$	$T_A = 70^\circ\text{C}$		100		μA
			$V_R = 50 \text{ V}$			50		
C_i	Input capacitance		$V_I = 0$	$f = 1 \text{ MHz}$		25		pF

5.6 Electrical Characteristics: ULN2003A and ULN2004A

$T_A = 25^\circ\text{C}$

PARAMETER	TEST FIGURE	TEST CONDITIONS	ULN2003A			ULN2004A			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
$V_{I(on)}$	Figure 6-6	$V_{CE} = 2 \text{ V}$	$I_C = 125 \text{ mA}$				5		V
			$I_C = 200 \text{ mA}$		2.4		6		
			$I_C = 250 \text{ mA}$		2.7				
			$I_C = 275 \text{ mA}$				7		
			$I_C = 300 \text{ mA}$		3				
			$I_C = 350 \text{ mA}$				8		
V_{OH}	High-level output voltage after switching	Figure 6-10	$V_S = 50 \text{ V}$	$I_O = 300 \text{ mA}$	$V_S - 20$	$V_S - 20$			mV
$V_{CE(sat)}$	Figure 6-5		$I_I = 250 \mu\text{A}$	$I_C = 100 \text{ mA}$	0.9	1.1	0.9	1.1	V
			$I_I = 350 \mu\text{A}$	$I_C = 200 \text{ mA}$	1	1.3	1	1.3	
			$I_I = 500 \mu\text{A}$	$I_C = 350 \text{ mA}$	1.2	1.6	1.2	1.6	
I_{CEX}	Figure 6-1	$V_{CE} = 50 \text{ V}$	$I_I = 0$		50		50		μA
		Figure 6-2	$V_{CE} = 50 \text{ V}$	$I_I = 0$	100		100		
			$T_A = 70^\circ\text{C}$	$V_I = 1 \text{ V}$		500			

5.6 Electrical Characteristics: ULN2003A and ULN2004A (continued)

$T_A = 25^\circ\text{C}$

PARAMETER	TEST FIGURE	TEST CONDITIONS	ULN2003A			ULN2004A			UNIT	
			MIN	TYP	MAX	MIN	TYP	MAX		
V_F	Clamp forward voltage	Figure 6-8	$I_F = 350 \text{ mA}$			1.7	2	1.7	2	V
$I_{I(\text{off})}$	Off-state input current	Figure 6-3	$V_{CE} = 50 \text{ V}$, $T_A = 70^\circ\text{C}$, $I_C = 500 \mu\text{A}$	50	65	50	65	50	65	μA
I_I	Input current	Figure 6-4	$V_I = 3.85 \text{ V}$			0.93	1.35			mA
			$V_I = 5 \text{ V}$					0.35	0.5	
			$V_I = 12 \text{ V}$					1	1.45	
I_R	Clamp reverse current	Figure 6-7	$V_R = 50 \text{ V}$			50		50		μA
			$V_R = 50 \text{ V}$, $T_A = 70^\circ\text{C}$			100		100		
C_i	Input capacitance		$V_I = 0$, $f = 1 \text{ MHz}$			15	25	15	25	pF

5.7 Electrical Characteristics: ULN2003AI

$T_A = 25^\circ\text{C}$

PARAMETER	TEST FIGURE	TEST CONDITIONS	ULN2003AI			UNIT	
			MIN	TYP	MAX		
$V_{I(\text{on})}$	ON-state input voltage	Figure 6-6	$I_C = 200 \text{ mA}$		2.4	V	
			$I_C = 250 \text{ mA}$		2.7		
			$I_C = 300 \text{ mA}$		3		
V_{OH}	High-level output voltage after switching	Figure 6-10	$V_S = 50 \text{ V}$, $I_O = 300 \text{ mA}$		$V_S - 50$	mV	
$V_{CE(\text{sat})}$	Collector-emitter saturation voltage	Figure 6-5	$I_I = 250 \mu\text{A}$, $I_C = 100 \text{ mA}$		0.9	1.1	V
			$I_I = 350 \mu\text{A}$, $I_C = 200 \text{ mA}$		1	1.3	
			$I_I = 500 \mu\text{A}$, $I_C = 350 \text{ mA}$		1.2	1.6	
I_{CEX}	Collector cutoff current	Figure 6-1	$V_{CE} = 50 \text{ V}$, $I_I = 0$		50	μA	
V_F	Clamp forward voltage	Figure 6-8	$I_F = 350 \text{ mA}$		1.7	2	V
$I_{I(\text{off})}$	OFF-state input current	Figure 6-3	$V_{CE} = 50 \text{ V}$, $I_C = 500 \mu\text{A}$	50	65		μA
I_I	Input current	Figure 6-4	$V_I = 3.85 \text{ V}$		0.93	1.35	mA
I_R	Clamp reverse current	Figure 6-7	$V_R = 50 \text{ V}$			50	μA
C_i	Input capacitance		$V_I = 0$, $f = 1 \text{ MHz}$		15	25	pF

5.8 Electrical Characteristics: ULN2003AI

$T_A = -40^\circ\text{C}$ to 105°C

PARAMETER	TEST FIGURE	TEST CONDITIONS	ULN2003AI			UNIT		
			MIN	TYP	MAX			
$V_{I(\text{on})}$	ON-state input voltage	Figure 6-6	$V_{CE} = 2 \text{ V}$	$I_C = 200 \text{ mA}$		2.7	V	
				$I_C = 250 \text{ mA}$		2.9		
				$I_C = 300 \text{ mA}$		3		
V_{OH}	High-level output voltage after switching	Figure 6-10	$V_S = 50 \text{ V}$, $I_O = 300 \text{ mA}$		$V_S - 50$	mV		
$V_{CE(\text{sat})}$	Collector-emitter saturation voltage	Figure 6-5		$I_I = 250 \mu\text{A}$, $I_C = 100 \text{ mA}$		0.9	1.2	V
				$I_I = 350 \mu\text{A}$, $I_C = 200 \text{ mA}$		1	1.4	
				$I_I = 500 \mu\text{A}$, $I_C = 350 \text{ mA}$		1.2	1.7	
I_{CEX}	Collector cutoff current	Figure 6-1	$V_{CE} = 50 \text{ V}$, $I_I = 0$		100	μA		

5.8 Electrical Characteristics: ULN2003AI (continued)

$T_A = -40^\circ\text{C}$ to 105°C

PARAMETER	TEST FIGURE	TEST CONDITIONS	ULN2003AI			UNIT	
			MIN	TYP	MAX		
V_F	Clamp forward voltage	Figure 6-8	$I_F = 350 \text{ mA}$		1.7	2.2	V
$I_{I(\text{off})}$	OFF-state input current	Figure 6-3	$V_{CE} = 50 \text{ V}$, $I_C = 500 \mu\text{A}$	30	65		μA
I_I	Input current	Figure 6-4	$V_I = 3.85 \text{ V}$		0.93	1.35	mA
I_R	Clamp reverse current	Figure 6-7	$V_R = 50 \text{ V}$		100		μA
C_i	Input capacitance		$V_I = 0$, $f = 1 \text{ MHz}$		15	25	pF

5.9 Electrical Characteristics: ULQ2003A and ULQ2004A

over recommended operating conditions (unless otherwise noted)

PARAMETER	TEST FIGURE	TEST CONDITIONS	ULQ2003A			ULQ2004A			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	
$V_{I(on)}$ ON-state input voltage	Figure 6-6	$V_{CE} = 2\text{ V}$	$I_C = 125\text{ mA}$					5	V
			$I_C = 200\text{ mA}$		2.7			6	
			$I_C = 250\text{ mA}$		2.9				
			$I_C = 275\text{ mA}$					7	
			$I_C = 300\text{ mA}$		3				
			$I_C = 350\text{ mA}$					8	
V_{OH}	High-level output voltage after switching	Figure 6-10	$V_S = 50\text{ V}, I_O = 300\text{ mA}$		$V_S - 50$		$V_S - 50$		mV
$V_{CE(sat)}$ Collector-emitter saturation voltage	Figure 6-5		$I_I = 250\text{ }\mu\text{A}, I_C = 100\text{ mA}$		0.9	1.2	0.9	1.1	V
			$I_I = 350\text{ }\mu\text{A}, I_C = 200\text{ mA}$		1	1.4	1	1.3	
			$I_I = 500\text{ }\mu\text{A}, I_C = 350\text{ mA}$		1.2	1.7	1.2	1.6	
I_{CEx} Collector cutoff current	Figure 6-1	$V_{CE} = 50\text{ V}, I_I = 0$			100		50		μA
		Figure 6-2	$V_{CE} = 50\text{ V}, T_A = 70^\circ\text{C}$	$I_I = 0$			100		
				$V_I = 1\text{ V}$			500		
V_F	Clamp forward voltage	Figure 6-8	$I_F = 350\text{ mA}$		1.7	2.3	1.7	2	V
$I_{I(off)}$	OFF-state input current	Figure 6-3	$V_{CE} = 50\text{ V}, T_A = 70^\circ\text{C},$	$I_C = 500\text{ }\mu\text{A}$	65		50	65	μA
I_I Input current	Figure 6-4	$V_I = 3.85\text{ V}$			0.93	1.35			mA
		$V_I = 5\text{ V}$					0.35	0.5	
		$V_I = 12\text{ V}$					1	1.45	
I_R Clamp reverse current	Figure 6-7	$V_R = 50\text{ V} T_A = 25^\circ\text{C}$			100		50		μA
		$V_R = 50\text{ V}$			100		100		
C_I	Input capacitance		$V_I = 0, f = 1\text{ MHz}$		15	25	15	25	pF

5.10 Switching Characteristics: ULN2002A, ULN2003A, ULN2004A

$T_A = 25^\circ\text{C}$

PARAMETER	TEST CONDITIONS	ULN2002A, ULN2003A, ULN2004A			UNIT
		MIN	TYP	MAX	
t_{PLH} Propagation delay time, low- to high-level output	See Figure 6-9		0.25	1	μs
t_{PHL} Propagation delay time, high- to low-level output	See Figure 6-9		0.25	1	μs

5.11 Switching Characteristics: ULN2003AI

$T_A = 25^\circ\text{C}$

PARAMETER	TEST CONDITIONS	ULN2003AI			UNIT
		MIN	TYP	MAX	
t_{PLH} Propagation delay time, low- to high-level output	See Figure 6-9		0.25	1	μs
t_{PHL} Propagation delay time, high- to low-level output	See Figure 6-9		0.25	1	μs

5.12 Switching Characteristics: ULN2003AI

$T_A = -40^\circ\text{C}$ to 105°C

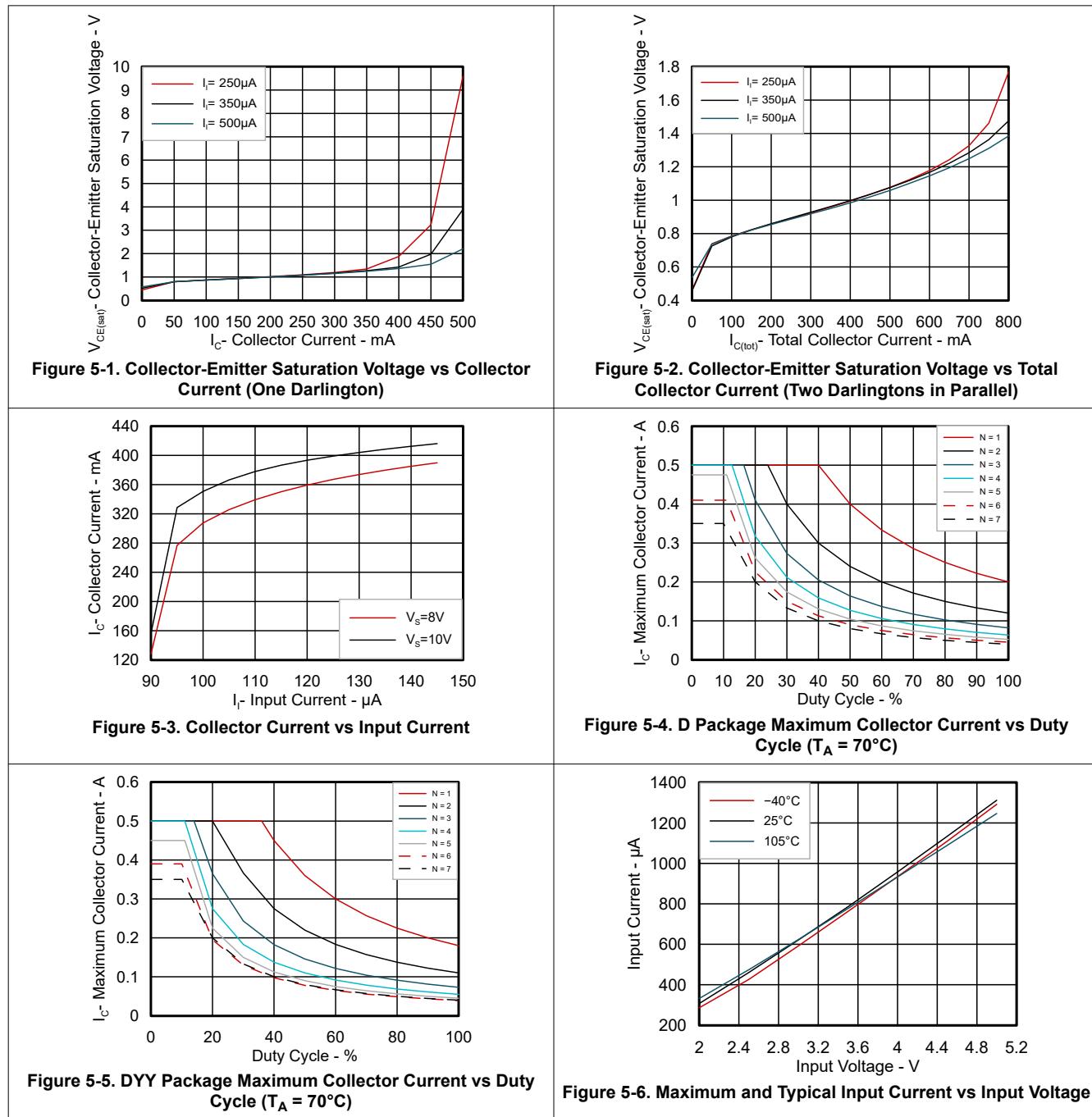
PARAMETER	TEST CONDITIONS	ULN2003AI			UNIT
		MIN	TYP	MAX	
t_{PLH}	Propagation delay time, low- to high-level output See Figure 6-9		1	10	μs
t_{PHL}	Propagation delay time, high- to low-level output See Figure 6-9		1	10	μs

5.13 Switching Characteristics: ULQ2003A, ULQ2004A

over recommended operating conditions (unless otherwise noted)

PARAMETER	TEST CONDITIONS	ULQ2003A, ULQ2004A			UNIT
		MIN	TYP	MAX	
t_{PLH}	Propagation delay time, low- to high-level output See Figure 6-9		1	10	μs
t_{PHL}	Propagation delay time, high- to low-level output See Figure 6-9		1	10	μs

5.14 Typical Characteristics



5.14 Typical Characteristics (continued)

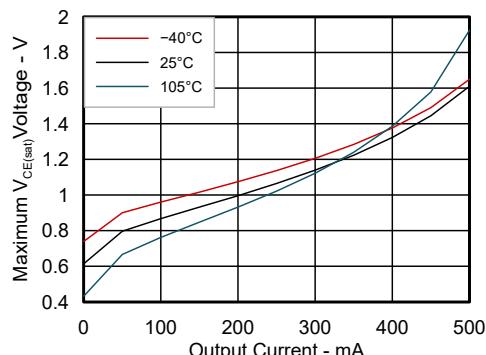


Figure 5-7. Maximum and Typical Saturated V_{CE} vs Output Current

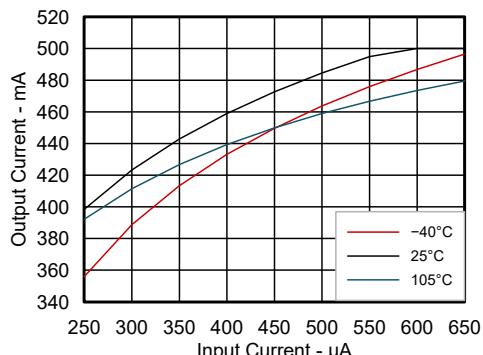


Figure 5-8. Minimum Output Current vs Input Current

6 Parameter Measurement Information

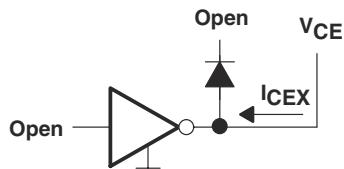


Figure 6-1. I_{CEx} Test Circuit

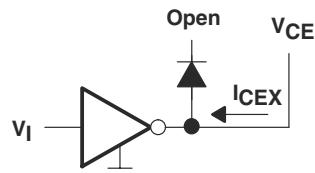


Figure 6-2. I_{CEx} Test Circuit

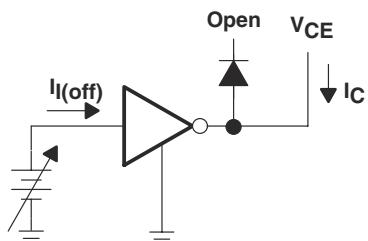


Figure 6-3. $I_{I(off)}$ Test Circuit

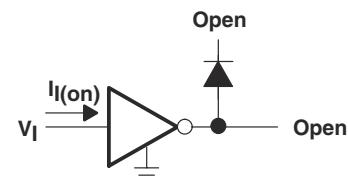
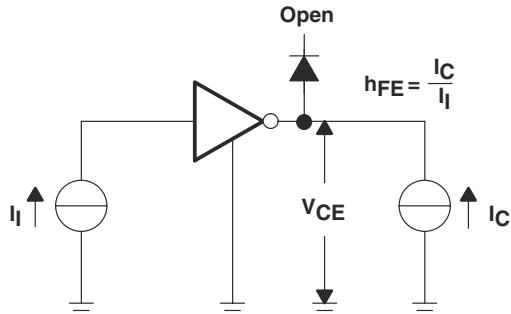


Figure 6-4. I_I Test Circuit



I_I is fixed for measuring $V_{CE(sat)}$, variable for measuring h_{FE} .

Figure 6-5. h_{FE} , $V_{CE(sat)}$ Test Circuit

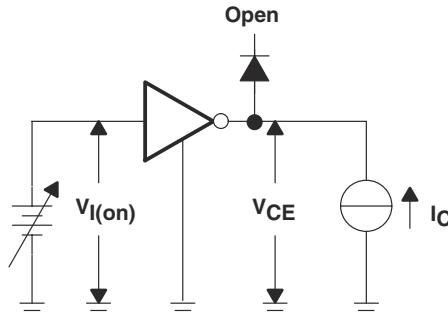


Figure 6-6. $V_{I(on)}$ Test Circuit

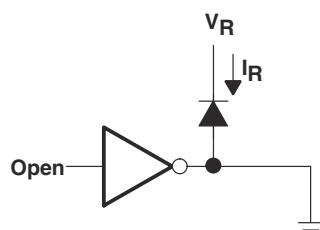


Figure 6-7. I_R Test Circuit

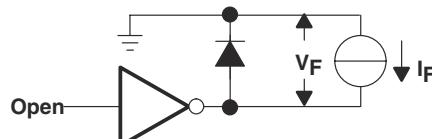


Figure 6-8. V_F Test Circuit

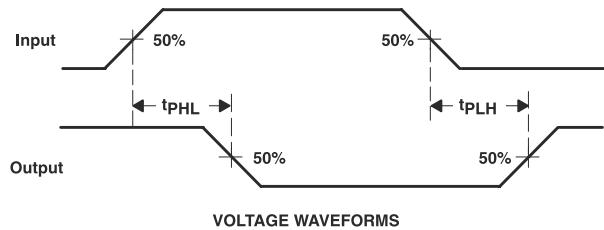
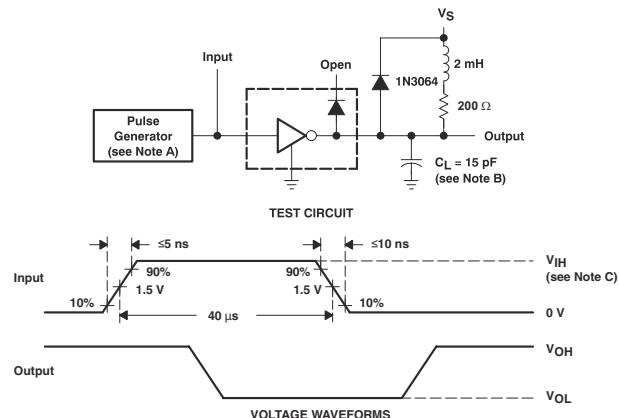


Figure 6-9. Propagation Delay-Time Waveforms



The pulse generator has the following characteristics: PRR = 12.5 kHz, $Z_0 = 50 \Omega$.

C_L includes probe and jig capacitance.

For testing the ULN2003A device, ULN2003AI device, and ULQ2003A devices, $V_{IH} = 3$ V; for the ULN2002A device, $V_{IH} = 13$ V; for the ULN2004A and the ULQ2004A devices, $V_{IH} = 8$ V.

Figure 6-10. Latch-Up Test Circuit and Voltage Waveforms

7 Detailed Description

7.1 Overview

This standard device has proven ubiquity and versatility across a wide range of applications. This is due to integration of 7 Darlington transistors of the device that are capable of sinking up to 500 mA and wide GPIO range capability.

The ULN2003A device comprises seven high-voltage, high-current NPN Darlington transistor pairs. All units feature a common emitter and open collector outputs. To maximize their effectiveness, these units contain suppression diodes for inductive loads. The ULN2003A device has a series base resistor to each Darlington pair, thus allowing operation directly with TTL or CMOS operating at supply voltages of 5 V or 3.3 V. The ULN2003A device offers solutions to a great many interface needs, including solenoids, relays, lamps, small motors, and LEDs. Applications requiring sink currents beyond the capability of a single output may be accommodated by paralleling the outputs.

This device can operate over a wide temperature range (-40°C to 105°C).

7.2 Functional Block Diagrams

All resistor values shown are nominal. The collector-emitter diode is a parasitic structure and should not be used to conduct current. If the collectors go below GND, an external Schottky diode should be added to clamp negative undershoots.

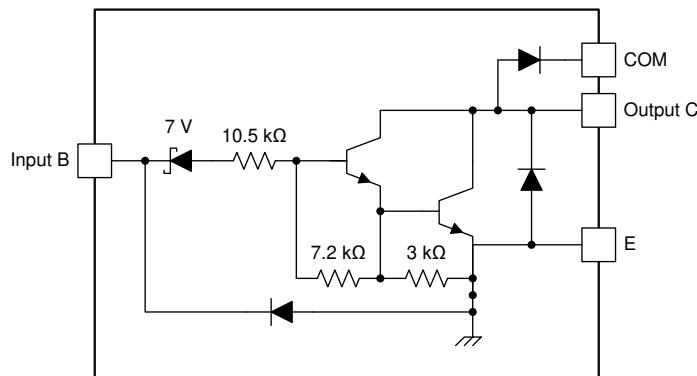


Figure 7-1. ULN2002A Block Diagram

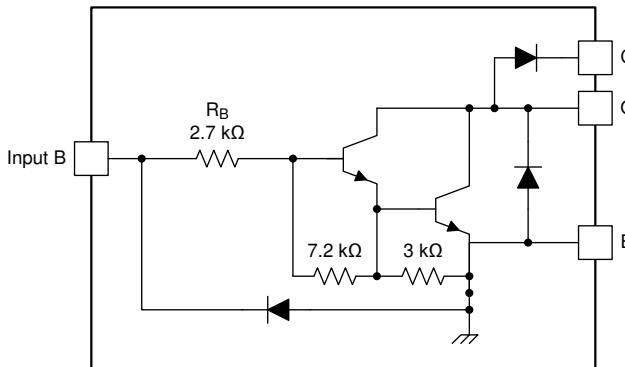


Figure 7-2. ULN2003A, ULQ2003A and ULN2003AI Block Diagram

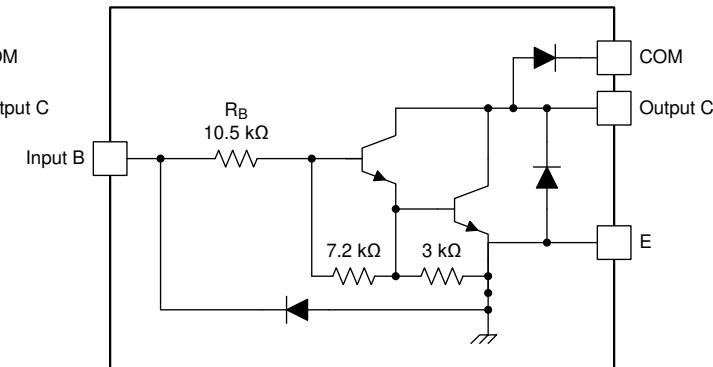


Figure 7-3. ULN2004A and LQ2004A Block Diagram

7.3 Feature Description

Each channel of the ULN2003A device consists of Darlington connected NPN transistors. This connection creates the effect of a single transistor with a very high-current gain (β_2). This can be as high as 10,000 A/A at certain currents. The very high β allows for high-output current drive with a very low input current, essentially equating to operation with low GPIO voltages.

The GPIO voltage is converted to base current through the 2.7-k Ω resistor connected between the input and base of the predriver Darlington NPN. The 7.2-k Ω and 3-k Ω resistors connected between the base and emitter of each respective NPN act as pulldowns and suppress the amount of leakage that may occur from the input.

The diodes connected between the output and COM pin is used to suppress the kick-back voltage from an inductive load that is excited when the NPN drivers are turned off (stop sinking) and the stored energy in the coils causes a reverse current to flow into the coil supply through the kick-back diode.

In normal operation the diodes on base and collector pins to emitter will be reversed biased. If these diodes are forward biased, internal parasitic NPN transistors will draw (a nearly equal) current from other (nearby) device pins.

7.4 Device Functional Modes

7.4.1 Inductive Load Drive

When the COM pin is tied to the coil supply voltage, ULN2003A device is able to drive inductive loads and suppress the kick-back voltage through the internal free-wheeling diodes.

7.4.2 Resistive Load Drive

When driving a resistive load, a pullup resistor is needed in order for ULN2003A device to sink current and for there to be a logic high level. The COM pin can be left floating for these applications.

8 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

8.1 Application Information

Typically, the ULN2003A device drives a high-voltage or high-current (or both) peripheral from an MCU or logic device that cannot tolerate these conditions. This design is a common application of ULN2003A device, driving inductive loads. This includes motors, solenoids and relays. [Figure 8-1](#) shows a model for each load type.

8.2 Typical Application

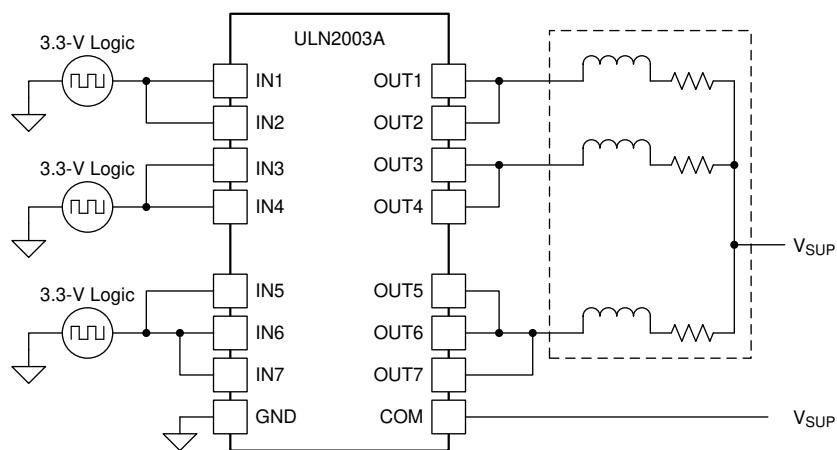


Figure 8-1. ULN2003A Device as Inductive Load Driver

8.2.1 Design Requirements

For this design example, use the parameters listed in [Table 8-1](#) as the input parameters.

Table 8-1. Design Parameters

DESIGN PARAMETER	EXAMPLE VALUE
GPIO voltage	3.3 V or 5 V
Coil supply voltage	12 V to 48 V
Number of channels	7
Output current (I_{COIL})	20 mA to 300 mA per channel
Duty cycle	100%

8.2.2 Detailed Design Procedure

When using ULN2003A device in a coil driving application, determine the following:

- Input voltage range
- Temperature range
- Output and drive current
- Power dissipation

8.2.2.1 Drive Current

The coil voltage (V_{SUP}), coil resistance (R_{COIL}), and low-level output voltage ($V_{CE(SAT)}$ or V_{OL}) determine the coil current.

$$I_{COIL} = (V_{SUP} - V_{CE(SAT)}) / R_{COIL} \quad (1)$$

8.2.2.2 Low-Level Output Voltage

The low-level output voltage (V_{OL}) is the same as $V_{CE(SAT)}$ and can be determined by, [Figure 5-1](#), [Figure 5-2](#), or [Figure 5-7](#).

8.2.2.3 Power Dissipation and Temperature

The number of coils driven is dependent on the coil current and on-chip power dissipation. The number of coils driven can be determined by [Figure 5-4](#) or [Figure 5-5](#).

For a more accurate determination of number of coils possible, use the below equation to calculate ULN2003A device on-chip power dissipation P_D :

$$P_D = \sum_{i=1}^N V_{OLi} \times I_{Li} \quad (2)$$

where

- N is the number of channels active together
- V_{OLi} is the OUT_i pin voltage for the load current I_{Li} . This is the same as $V_{CE(SAT)}$

To ensure reliability of ULN2003A device and the system, the on-chip power dissipation must be lower than or equal to the maximum allowable power dissipation ($PD_{(MAX)}$) dictated by below equation [Equation 3](#).

$$PD_{(MAX)} = \frac{(T_{J(MAX)} - T_A)}{\theta_{JA}} \quad (3)$$

where

- $T_{J(MAX)}$ is the target maximum junction temperature
- T_A is the operating ambient temperature
- θ_{JA} is the package junction to ambient thermal resistance

Limit the die junction temperature of the ULN2003A device to less than 125°C. The IC junction temperature is directly proportional to the on-chip power dissipation.

8.2.3 Application Curves

The characterization data shown in [Figure 8-2](#) and [Figure 8-3](#) were generated using the ULN2003A device driving an OMRON G5NB relay and under the following conditions: $V_{IN} = 5$ V, $V_{SUP} = 12$ V, and $R_{COIL} = 2.8$ k Ω .

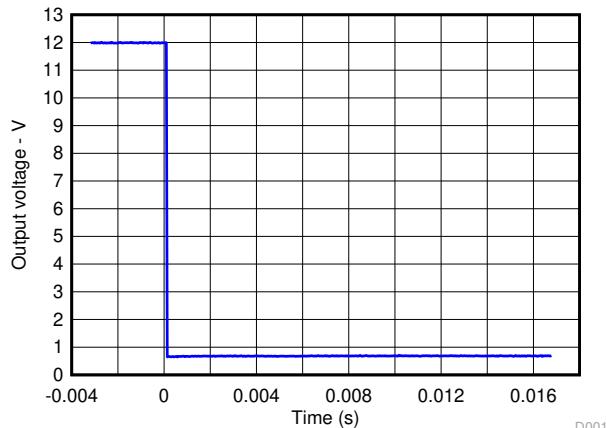


Figure 8-2. Output Response With Activation of Coil (Turnon)

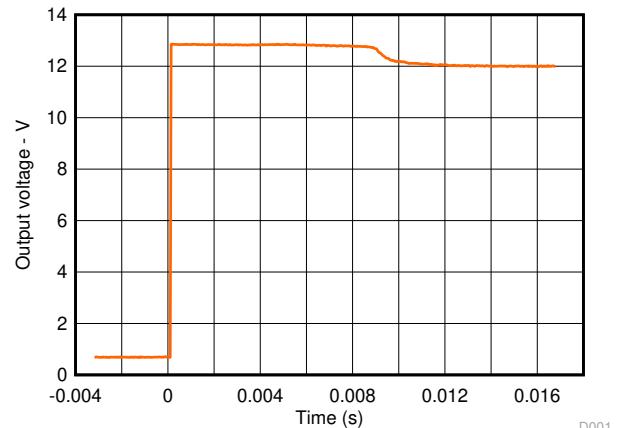


Figure 8-3. Output Response With De-activation of Coil (Turnoff)

8.3 System Examples

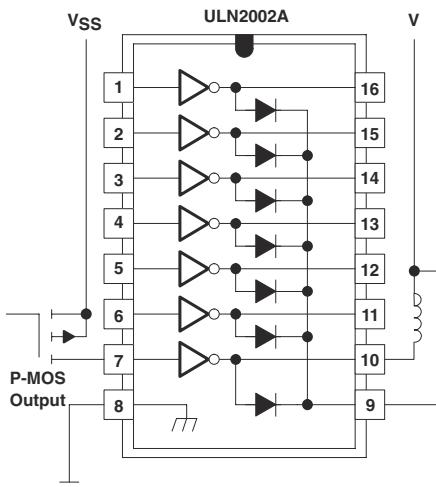


Figure 8-4. P-MOS to Load

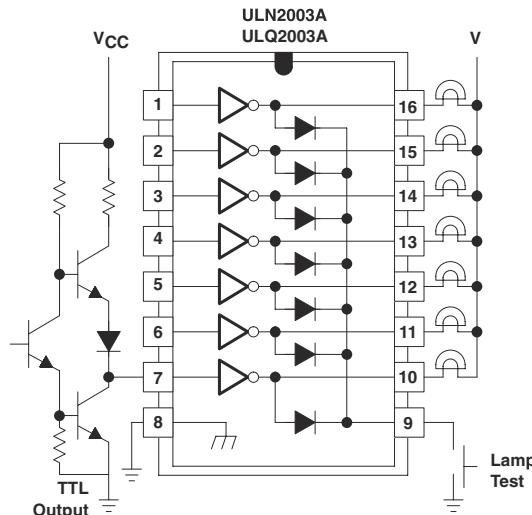


Figure 8-5. TTL to Load

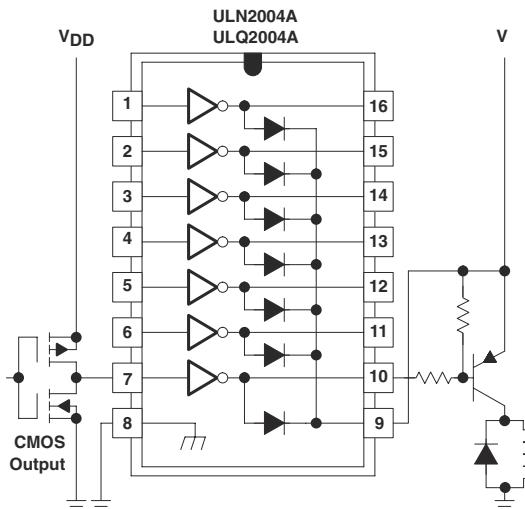


Figure 8-6. Buffer for Higher Current Loads

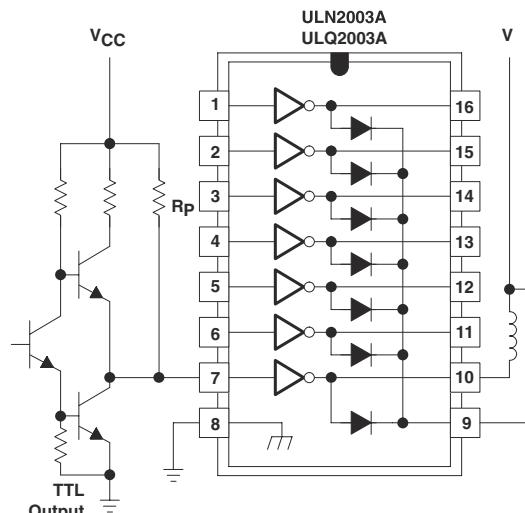


Figure 8-7. Use of Pullup Resistors to Increase Drive Current

8.4 Power Supply Recommendations

This device does not need a power supply. However, the COM pin is typically tied to the system power supply. When this is the case, it is very important to ensure that the output voltage does not heavily exceed the COM pin voltage. This discrepancy heavily forward biases the fly-back diodes and causes a large current to flow into COM, potentially damaging the on-chip metal or over-heating the device.

8.5 Layout

8.5.1 Layout Guidelines

Thin traces can be used on the input due to the low-current logic that is typically used to drive ULN2003A device. Take care to separate the input channels as much as possible, as to eliminate crosstalk. TI recommends thick traces for the output to drive whatever high currents that may be needed. Wire thickness can be determined by the current density of the trace material and desired drive current.

Because all of the channels currents return to a common emitter, it is best to size that trace width to be very wide. Some applications require up to 2.5 A.

8.5.2 Layout Example

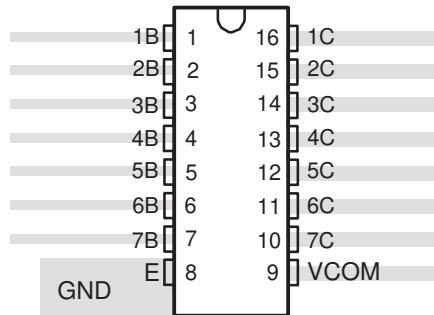


Figure 8-8. Package Layout

9 Device and Documentation Support

9.1 Documentation Support

9.1.1 Related Documentation

For related documentation, see the following:

SN7546x Darlington Transistor Arrays, [SLRS023](#)

9.2 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 9-1. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
ULN2002A	Click here				
ULN2003A	Click here				
ULN2003AI	Click here				
ULN2004A	Click here				
ULQ2003A	Click here				
ULQ2004A	Click here				

9.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on [ti.com](#). Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

9.4 Support Resources

[TI E2E™ support forums](#) are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

9.5 Trademarks

TI E2E™ is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

9.6 Electrostatic Discharge Caution

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.



ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

9.7 Glossary

[TI Glossary](#) This glossary lists and explains terms, acronyms, and definitions.

10 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision S (June 2024) to Revision T (March 2025)	Page
---	-------------

- Added ULN2004ADR MIN = -40°C and MAX = 105°C for T_A in the *Absolute Maximum Ratings* table.....[4](#)

- Changed I_{CEX} test condition From: $V_I = 6V$ To: $V_I = 1V$ in the *Electrical Characteristics: ULN2003A and ULN2004A* table..... [5](#)

Changes from Revision R (February 2024) to Revision S (June 2024)	Page
• Added DYY package throughout the data sheet.....	1

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical packaging and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser based versions of this data sheet, refer to the left hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
ULN2002AN	Active	Production	PDIP (N) 16	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-20 to 70	ULN2002AN
ULN2002AN.A	Active	Production	PDIP (N) 16	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-20 to 70	ULN2002AN
ULN2002ANE4	Active	Production	PDIP (N) 16	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-20 to 70	ULN2002AN
ULN2003ADR	Active	Production	SOIC (D) 16	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 70	ULN2003A
ULN2003ADR.A	Active	Production	SOIC (D) 16	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 70	ULN2003A
ULN2003ADYYR	Active	Production	SOT-23-THIN (DYY) 16	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 70	UN2003A
ULN2003ADYYR.A	Active	Production	SOT-23-THIN (DYY) 16	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 70	UN2003A
ULN2003AIDR	Active	Production	SOIC (D) 16	2500 LARGE T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	-40 to 105	ULN2003AI
ULN2003AIDR.A	Active	Production	SOIC (D) 16	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 105	ULN2003AI
ULN2003AIN	Obsolete	Production	PDIP (N) 16	-	-	Call TI	Call TI	-40 to 105	ULN2003AIN
ULN2003AINSR	Active	Production	SOP (NS) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 105	ULN2003AI
ULN2003AINSR.A	Active	Production	SOP (NS) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 105	ULN2003AI
ULN2003AIPW	Obsolete	Production	TSSOP (PW) 16	-	-	Call TI	Call TI	-40 to 105	UN2003AI
ULN2003AIPWR	Active	Production	TSSOP (PW) 16	2000 LARGE T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	-40 to 105	(U2003AI, UN2003AI)
ULN2003AIPWR.A	Active	Production	TSSOP (PW) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 105	(U2003AI, UN2003AI)
ULN2003AIPWRG4	Obsolete	Production	TSSOP (PW) 16	-	-	Call TI	Call TI	-40 to 105	UN2003AI
ULN2003AN	Active	Production	PDIP (N) 16	25 TUBE	Yes	NIPDAU SN	N/A for Pkg Type	-40 to 70	ULN2003AN
ULN2003AN.A	Active	Production	PDIP (N) 16	25 TUBE	Yes	NIPDAU SN	N/A for Pkg Type	-40 to 70	ULN2003AN
ULN2003ANS	Obsolete	Production	SOP (NS) 16	-	-	Call TI	Call TI	-40 to 70	ULN2003A
ULN2003ANSR	Active	Production	SOP (NS) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 70	ULN2003A
ULN2003ANSR.A	Active	Production	SOP (NS) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 70	ULN2003A
ULN2003ANSRE4	Active	Production	SOP (NS) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 70	ULN2003A
ULN2003ANSRG4	Active	Production	SOP (NS) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 70	ULN2003A
ULN2003APW	Obsolete	Production	TSSOP (PW) 16	-	-	Call TI	Call TI	-40 to 70	UN2003A
ULN2003APWR	Active	Production	TSSOP (PW) 16	2000 LARGE T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	-40 to 70	UN2003A
ULN2003APWR.A	Active	Production	TSSOP (PW) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 70	UN2003A

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
ULN2003APWRG4	Obsolete	Production	TSSOP (PW) 16	-	-	Call TI	Call TI	-40 to 70	UN2003A
ULN2004AD	Obsolete	Production	SOIC (D) 16	-	-	Call TI	Call TI	-20 to 70	ULN2004A
ULN2004ADR	Active	Production	SOIC (D) 16	2500 LARGE T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	-20 to 70	ULN2004A
ULN2004ADR.A	Active	Production	SOIC (D) 16	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-20 to 70	ULN2004A
ULN2004ADRG4	Obsolete	Production	SOIC (D) 16	-	-	Call TI	Call TI	-20 to 70	ULN2004A
ULN2004ADYYR	Active	Production	SOT-23-THIN (DYY) 16	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 70	UN2004A
ULN2004ADYYR.A	Active	Production	SOT-23-THIN (DYY) 16	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 70	UN2004A
ULN2004AN	Active	Production	PDIP (N) 16	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-20 to 70	ULN2004AN
ULN2004AN.A	Active	Production	PDIP (N) 16	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-20 to 70	ULN2004AN
ULN2004ANE4	Active	Production	PDIP (N) 16	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-20 to 70	ULN2004AN
ULN2004ANSR	Active	Production	SOP (NS) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-20 to 70	ULN2004A
ULN2004ANSR.A	Active	Production	SOP (NS) 16	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-20 to 70	ULN2004A
ULQ2003AD	Obsolete	Production	SOIC (D) 16	-	-	Call TI	Call TI	-40 to 85	ULQ2003A
ULQ2003ADG4	Obsolete	Production	SOIC (D) 16	-	-	Call TI	Call TI	-	ULQ2003A
ULQ2003AN	Active	Production	PDIP (N) 16	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	ULQ2003A
ULQ2003AN.A	Active	Production	PDIP (N) 16	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	ULQ2003A
ULQ2004AD	Active	Production	SOIC (D) 16	40 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ULQ2004A
ULQ2004AD.A	Active	Production	SOIC (D) 16	40 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ULQ2004A
ULQ2004ADG4	Active	Production	SOIC (D) 16	40 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-	ULQ2004A
ULQ2004ADG4.A	Active	Production	SOIC (D) 16	40 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ULQ2004A
ULQ2004ADR	Active	Production	SOIC (D) 16	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ULQ2004A
ULQ2004ADR.A	Active	Production	SOIC (D) 16	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ULQ2004A
ULQ2004ADRG4	Active	Production	SOIC (D) 16	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-	ULQ2004A
ULQ2004ADRG4.A	Active	Production	SOIC (D) 16	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	ULQ2004A
ULQ2004AN	Active	Production	PDIP (N) 16	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	ULQ2004AN
ULQ2004AN.A	Active	Production	PDIP (N) 16	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	ULQ2004AN

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

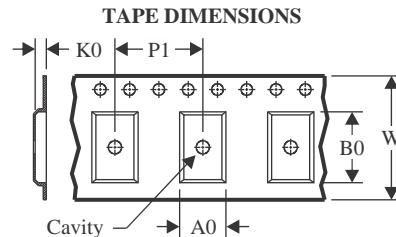
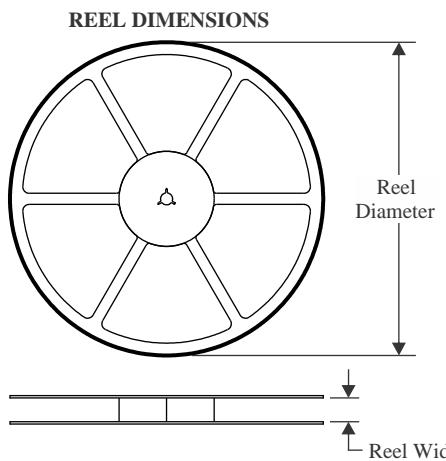
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF ULQ2003A, ULQ2004A :

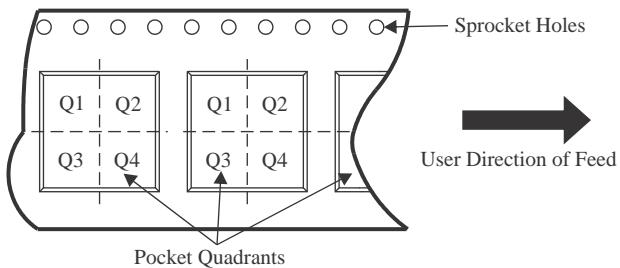
- Automotive : [ULQ2003A-Q1](#), [ULQ2004A-Q1](#)

NOTE: Qualified Version Definitions:

- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

TAPE AND REEL INFORMATION

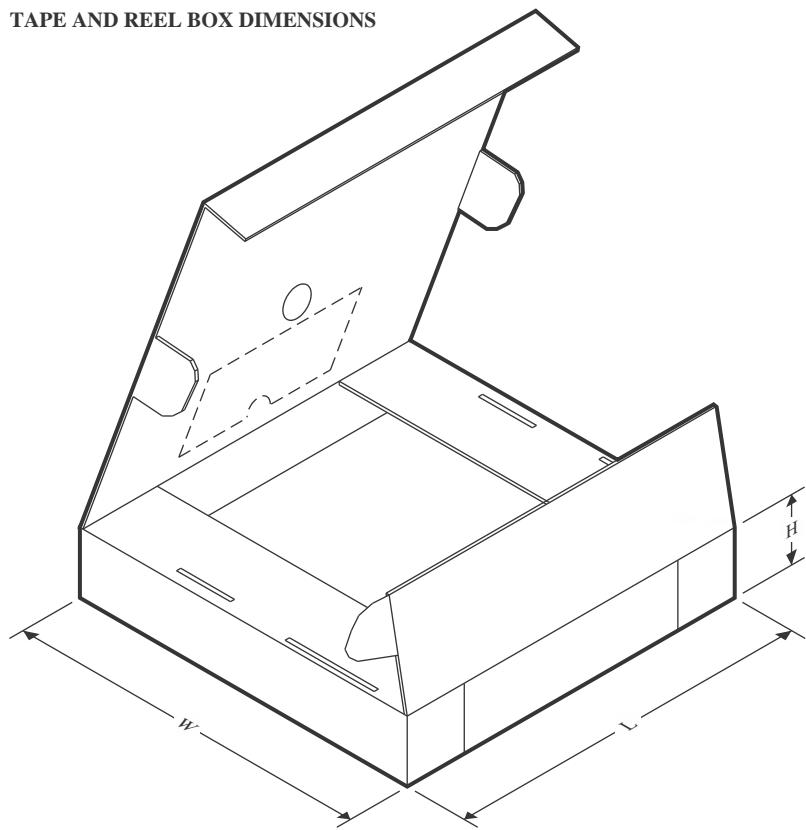
A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
ULN2003ADR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
ULN2003ADR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
ULN2003ADYXR	SOT-23-THIN	DYY	16	3000	330.0	12.4	4.8	3.6	1.6	8.0	12.0	Q3
ULN2003AIDR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
ULN2003AIDR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
ULN2003AINSR	SOP	NS	16	2000	330.0	16.4	8.1	10.4	2.5	12.0	16.0	Q1
ULN2003AINSR	SOP	NS	16	2000	330.0	16.4	8.45	10.55	2.5	12.0	16.2	Q1
ULN2003AIPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
ULN2003AIPWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
ULN2003ANSR	SOP	NS	16	2000	330.0	16.4	8.1	10.4	2.5	12.0	16.0	Q1
ULN2003ANSR	SOP	NS	16	2000	330.0	16.4	8.45	10.55	2.5	12.0	16.2	Q1
ULN2003APWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
ULN2003APWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
ULN2004ADR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
ULN2004ADR	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1

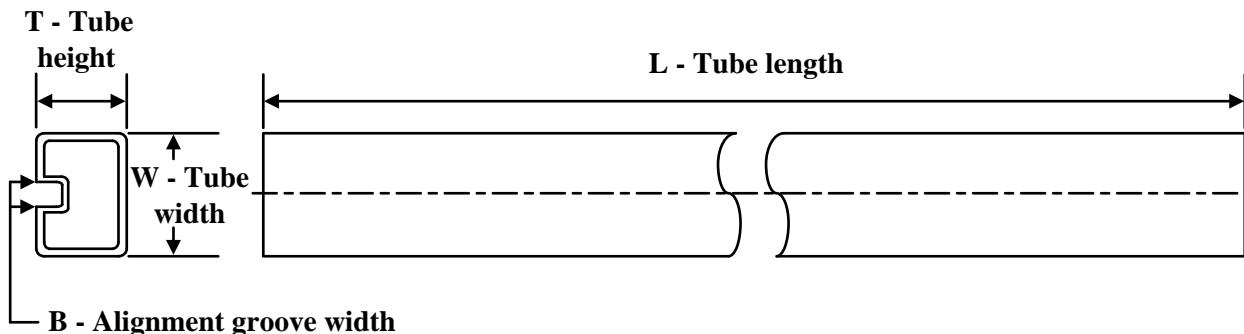
Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
ULN2004ADYYR	SOT-23-THIN	DYY	16	3000	330.0	12.4	4.8	3.6	1.6	8.0	12.0	Q3
ULN2004ANSR	SOP	NS	16	2000	330.0	16.4	8.1	10.4	2.5	12.0	16.0	Q1

TAPE AND REEL BOX DIMENSIONS


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
ULN2003ADR	SOIC	D	16	2500	340.5	336.1	32.0
ULN2003ADR	SOIC	D	16	2500	353.0	353.0	32.0
ULN2003ADYYR	SOT-23-THIN	DYY	16	3000	336.6	336.6	31.8
ULN2003AIDR	SOIC	D	16	2500	340.5	336.1	32.0
ULN2003AIDR	SOIC	D	16	2500	353.0	353.0	32.0
ULN2003AINSR	SOP	NS	16	2000	353.0	353.0	32.0
ULN2003AINSR	SOP	NS	16	2000	353.0	353.0	32.0
ULN2003AIPWR	TSSOP	PW	16	2000	353.0	353.0	32.0
ULN2003AIPWR	TSSOP	PW	16	2000	353.0	353.0	32.0
ULN2003ANSR	SOP	NS	16	2000	353.0	353.0	32.0
ULN2003ANSR	SOP	NS	16	2000	353.0	353.0	32.0
ULN2003APWR	TSSOP	PW	16	2000	353.0	353.0	32.0
ULN2003APWR	TSSOP	PW	16	2000	353.0	353.0	32.0
ULN2004ADR	SOIC	D	16	2500	340.5	336.1	32.0
ULN2004ADR	SOIC	D	16	2500	353.0	353.0	32.0
ULN2004ADYYR	SOT-23-THIN	DYY	16	3000	336.6	336.6	31.8
ULN2004ANSR	SOP	NS	16	2000	353.0	353.0	32.0

TUBE

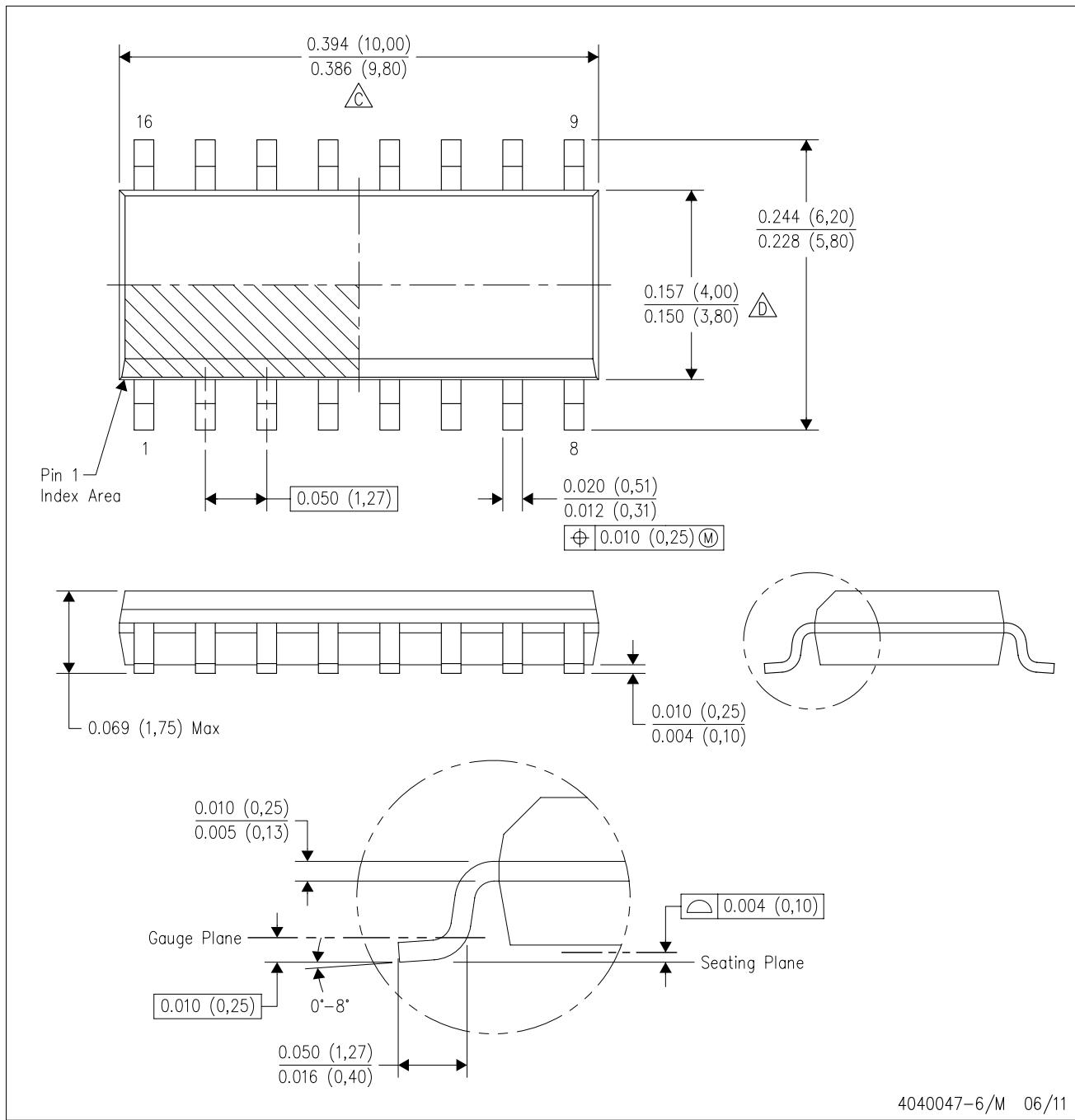


*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μ m)	B (mm)
ULN2002AN	N	PDIP	16	25	506	13.97	11230	4.32
ULN2002AN.A	N	PDIP	16	25	506	13.97	11230	4.32
ULN2002ANE4	N	PDIP	16	25	506	13.97	11230	4.32
ULN2003AN	N	PDIP	16	25	506.1	9	600	5.4
ULN2003AN	N	PDIP	16	25	506	13.97	11230	4.32
ULN2003AN	N	PDIP	16	25	506	13.97	11230	4.32
ULN2003AN.A	N	PDIP	16	25	506.1	9	600	5.4
ULN2003AN.A	N	PDIP	16	25	506	13.97	11230	4.32
ULN2003AN.A	N	PDIP	16	25	506	13.97	11230	4.32
ULN2004AN	N	PDIP	16	25	506	13.97	11230	4.32
ULN2004AN	N	PDIP	16	25	506	13.97	11230	4.32
ULN2004AN.A	N	PDIP	16	25	506	13.97	11230	4.32
ULN2004AN.A	N	PDIP	16	25	506	13.97	11230	4.32
ULN2004ANE4	N	PDIP	16	25	506	13.97	11230	4.32
ULN2004ANE4	N	PDIP	16	25	506	13.97	11230	4.32
ULQ2003AN	N	PDIP	16	25	506	13.97	11230	4.32
ULQ2003AN	N	PDIP	16	25	506	13.97	11230	4.32
ULQ2003AN.A	N	PDIP	16	25	506	13.97	11230	4.32
ULQ2003AN.A	N	PDIP	16	25	506	13.97	11230	4.32
ULQ2004AD	D	SOIC	16	40	507	8	3940	4.32
ULQ2004AD.A	D	SOIC	16	40	507	8	3940	4.32
ULQ2004ADG4	D	SOIC	16	40	507	8	3940	4.32
ULQ2004ADG4.A	D	SOIC	16	40	507	8	3940	4.32
ULQ2004AN	N	PDIP	16	25	506	13.97	11230	4.32
ULQ2004AN.A	N	PDIP	16	25	506	13.97	11230	4.32

D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.

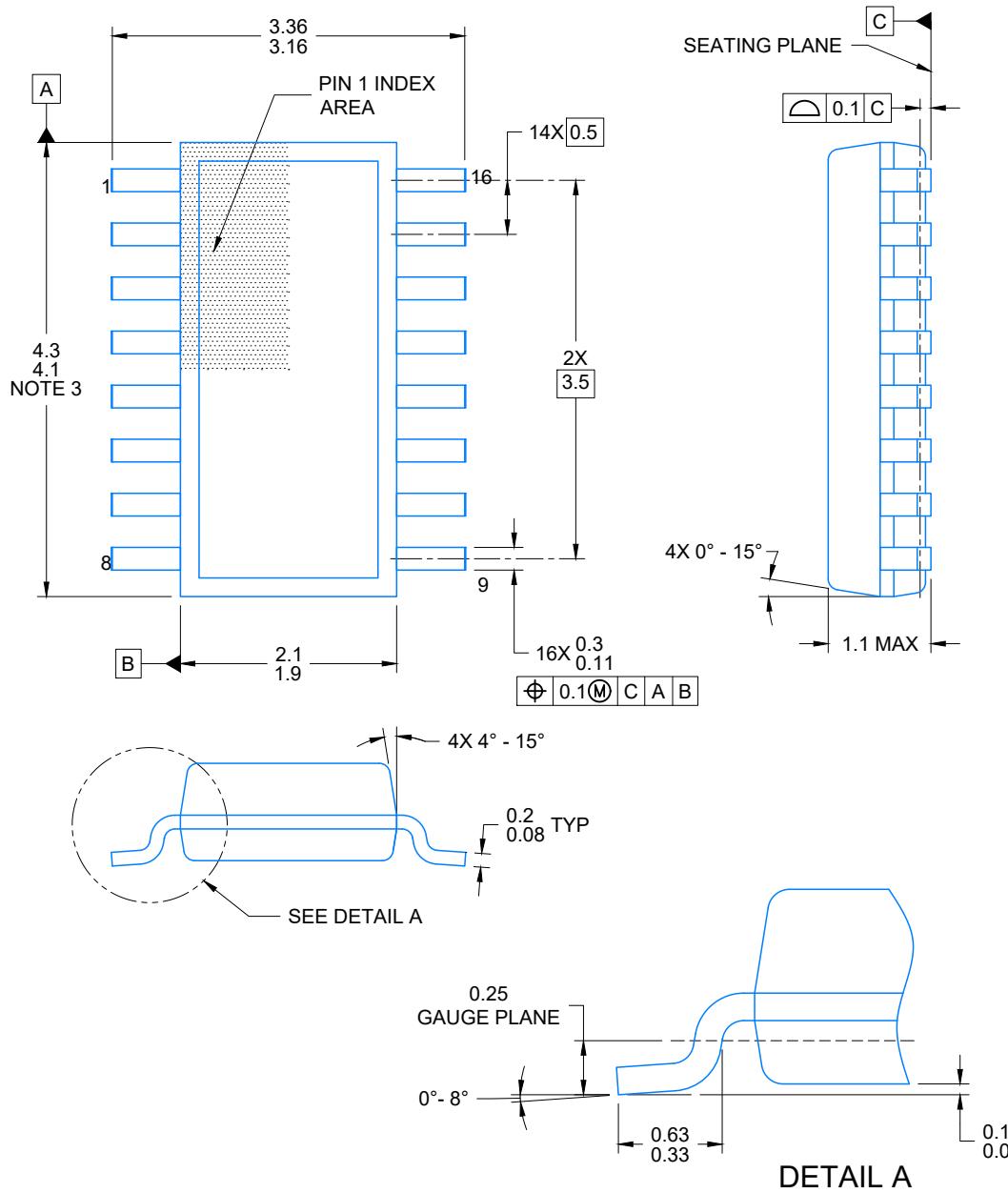
D Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
E. Reference JEDEC MS-012 variation AC.

4040047-6/M 06/11

PACKAGE OUTLINE

SOT-23-THIN - 1.1 mm max height

PLASTIC SMALL OUTLINE



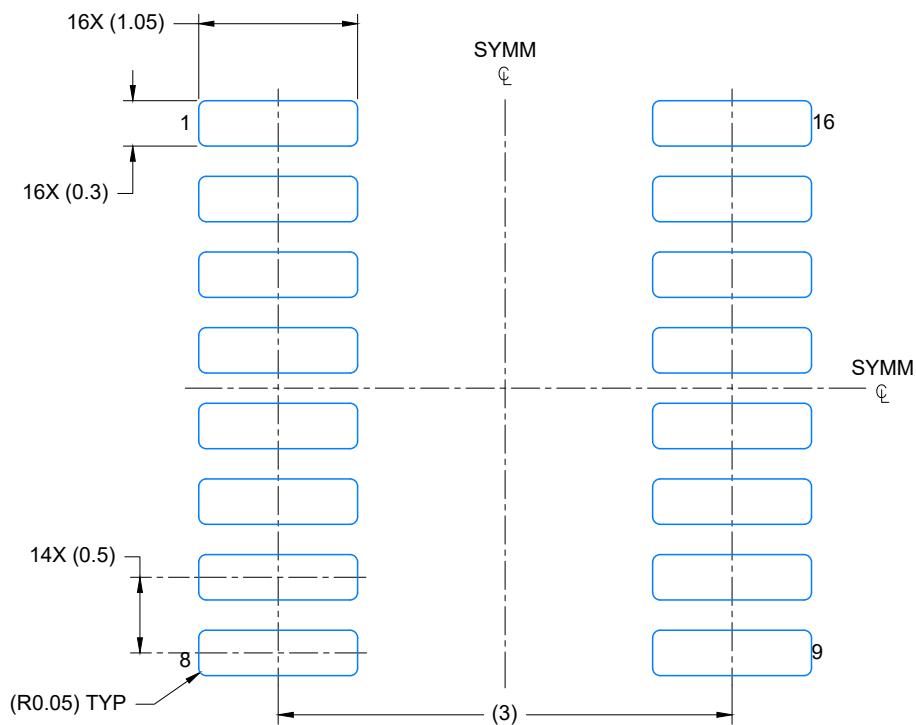
4224642/D 07/2024

NOTES:

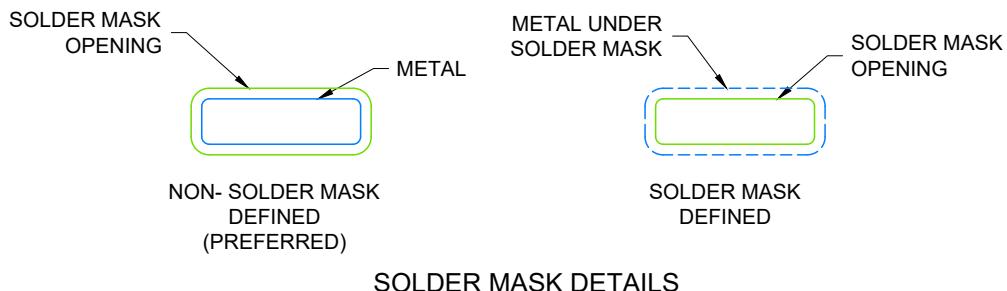
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 2. This drawing is subject to change without notice.
 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per side.
 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
 5. Reference JEDEC Registration MO-345, Variation AA



PLASTIC SMALL OUTLINE



LAND PATTERN EXAMPLE
 EXPOSED METAL SHOWN
 SCALE: 20X



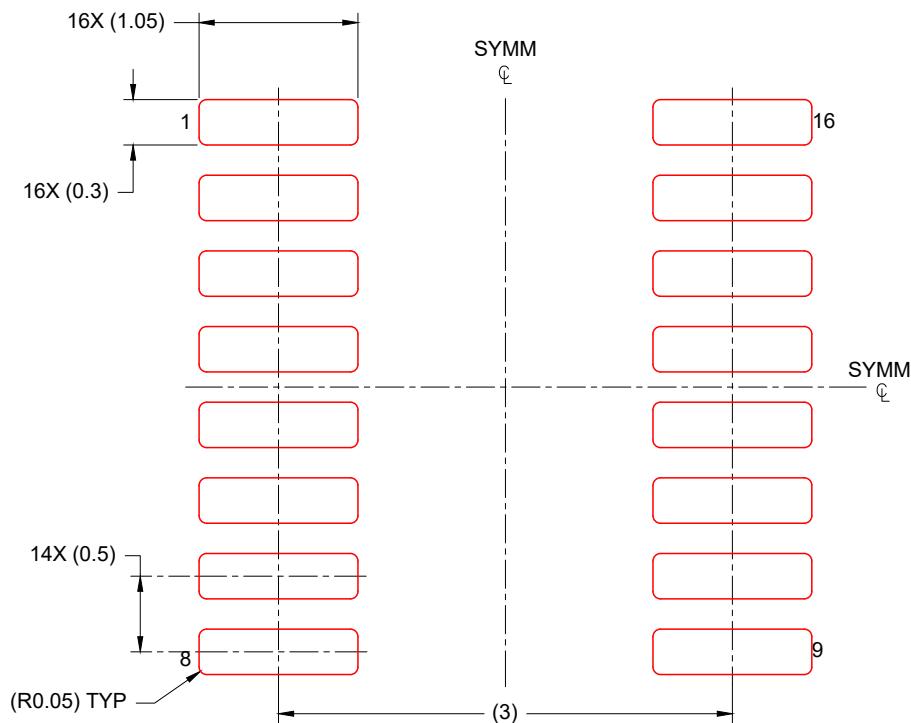
SOLDER MASK DETAILS

4224642/D 07/2024

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

PLASTIC SMALL OUTLINE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 20X

4224642/D 07/2024

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

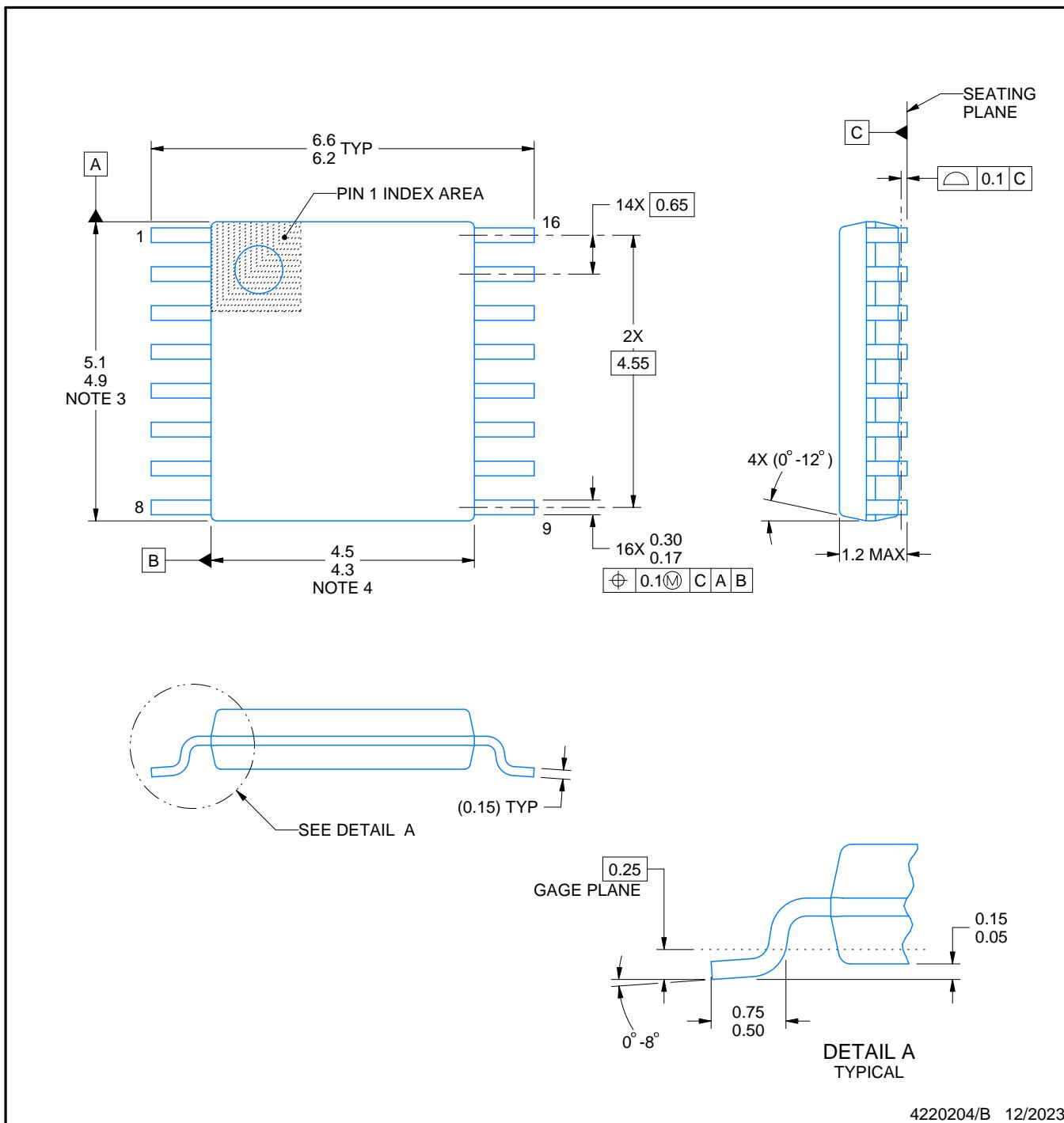
PACKAGE OUTLINE

PW0016A



TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

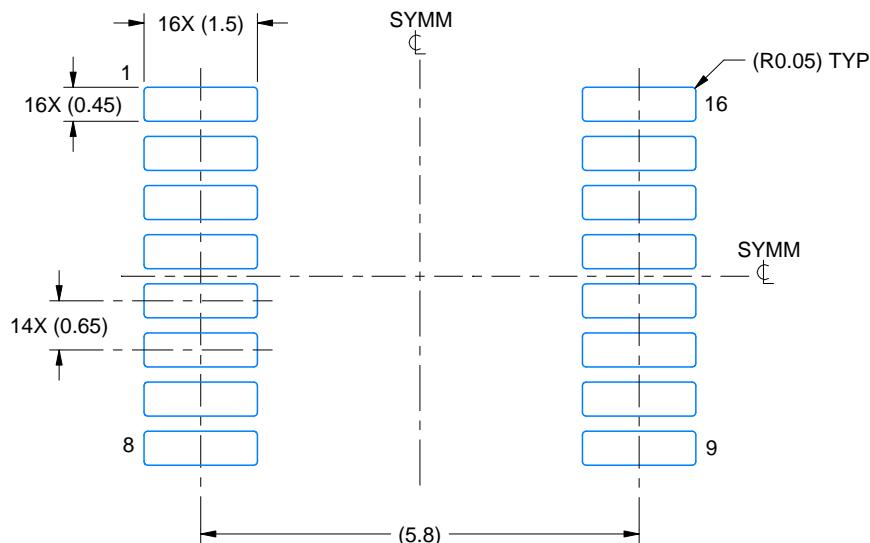
- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- This drawing is subject to change without notice.
- This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
- This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- Reference JEDEC registration MO-153.

EXAMPLE BOARD LAYOUT

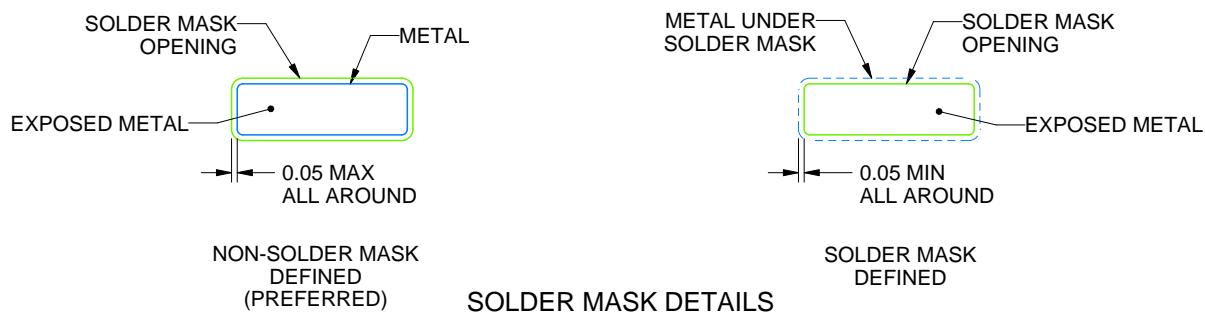
PW0016A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X



4220204/B 12/2023

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

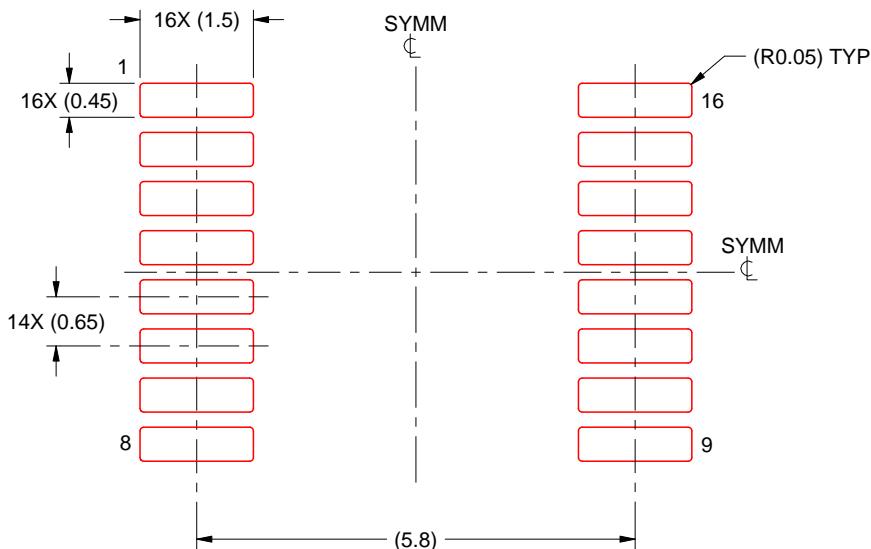
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

PW0016A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4220204/B 12/2023

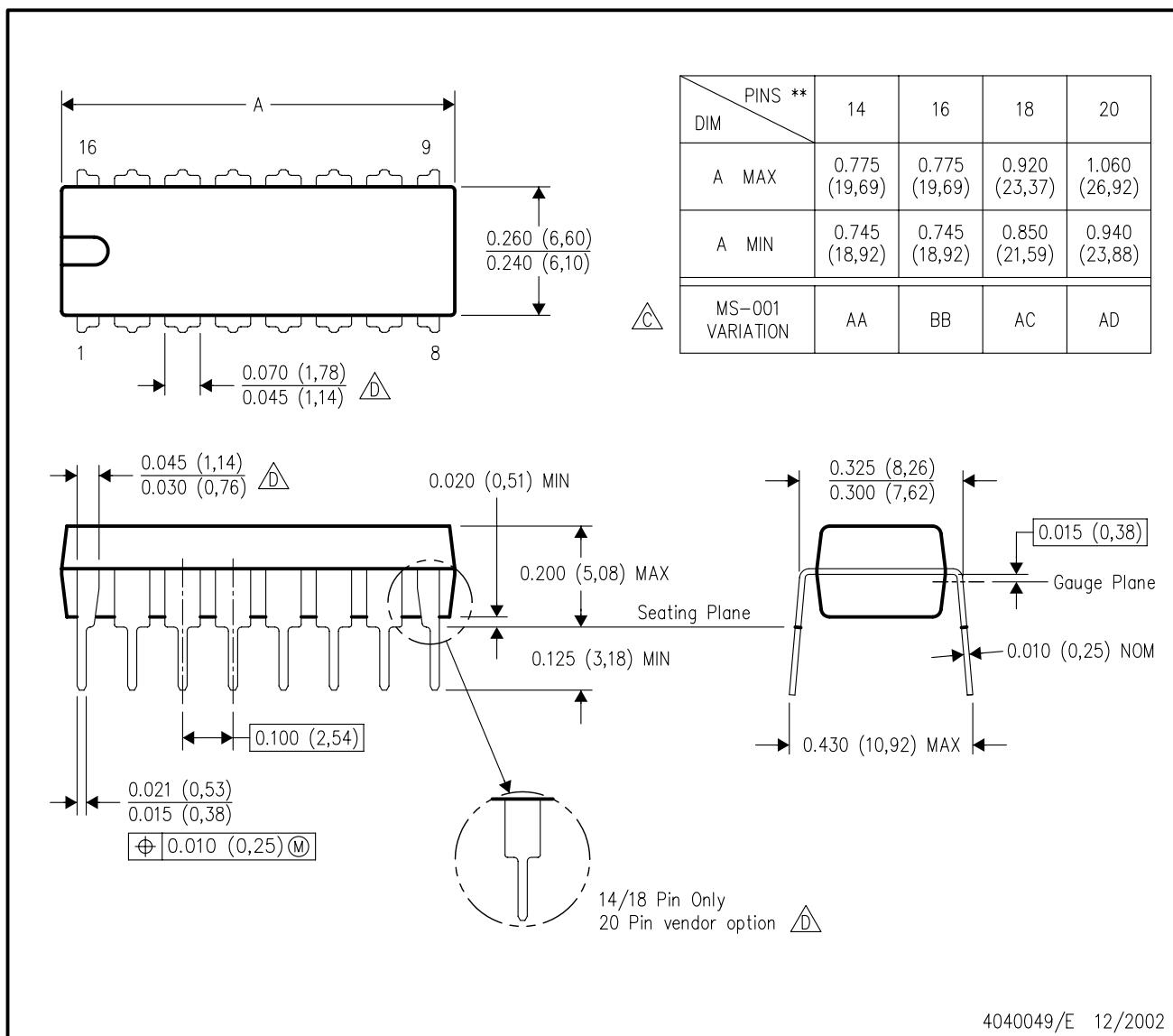
NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

N (R-PDIP-T**)

16 PINS SHOWN

PLASTIC DUAL-IN-LINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.

C. Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).

D. The 20 pin end lead shoulder width is a vendor option, either half or full width.

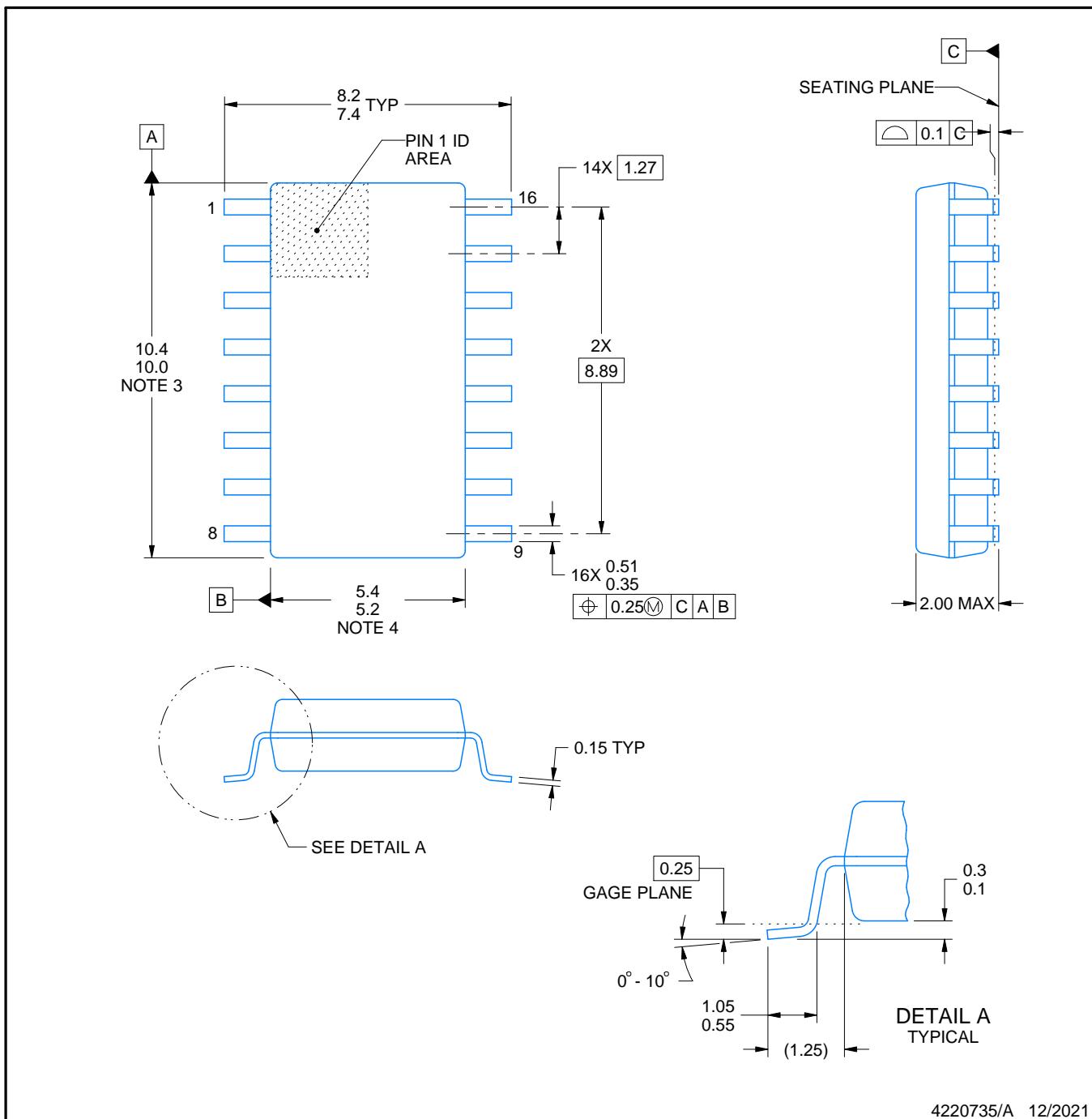
NS0016A



PACKAGE OUTLINE

SOP - 2.00 mm max height

SOP



NOTES:

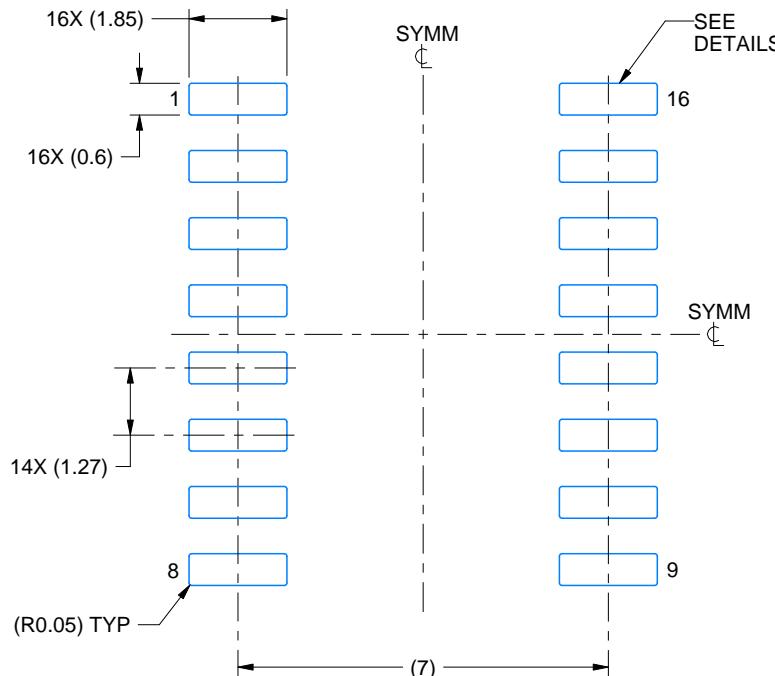
1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm, per side.

EXAMPLE BOARD LAYOUT

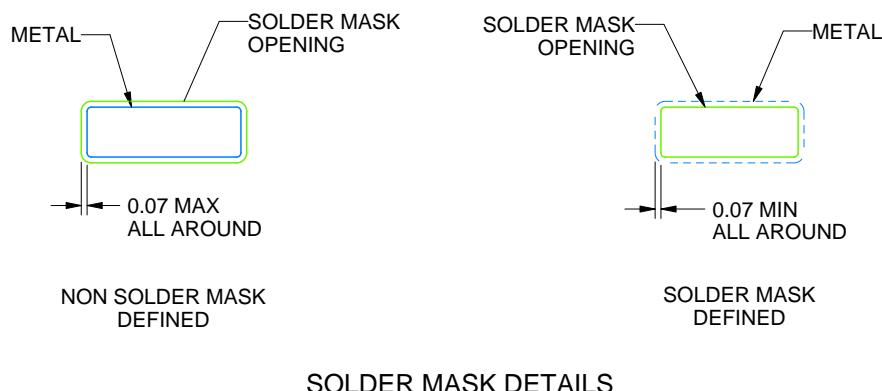
NS0016A

SOP - 2.00 mm max height

SOP



LAND PATTERN EXAMPLE
SCALE:7X



4220735/A 12/2021

NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.

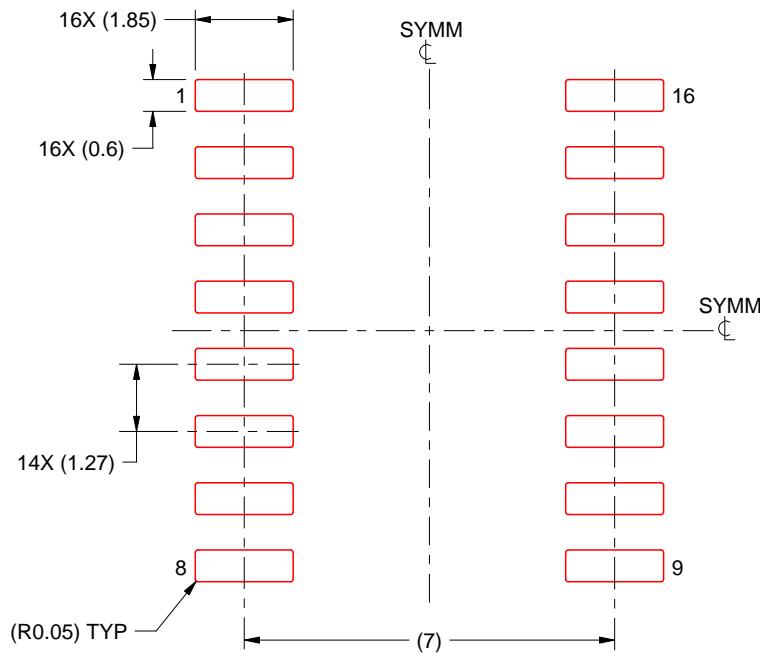
6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

NS0016A

SOP - 2.00 mm max height

SOP



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:7X

4220735/A 12/2021

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.

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Last updated 10/2025